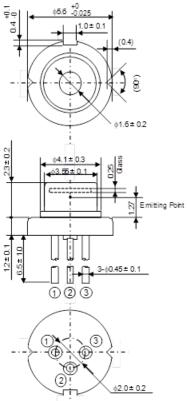


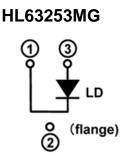
# HL63253MG

# 637nm/450mW AlGaInP Laser Diode

# Outline



**Internal Circuit** 



(Unit: mm)

#### **Features**

- Shorter wavelength: 637nm Typ.
- High optical output power: 450mW
- Low operating current: 600mA Typ.
- Multi transverse mode
- TM mode oscillation

#### Application

- Bio & Medical
- Measurement



# Absolute Maximum Ratings (Tc=25°C)

Item	Symbol	Ratings	Unit
Optical output power	Po	450	mW
LD Reverse Voltage	VR(LD)	2	V
Operating Temperature Note1)	Topr	-10 ~ +40	°C
Storage Temperature	Tstg	-40 ~ +85	°C

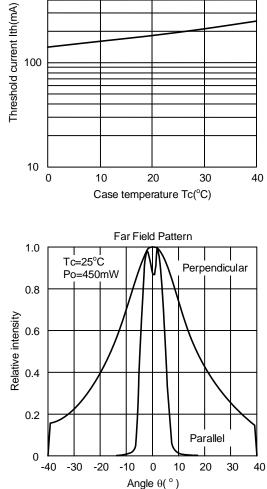
Note1) Operating temperature is defined by Case temperature "Tc". High increase in temperature of LD chip itself is expected during operation due to high current density. Thus, without proper heat dissipation, it is observed that no specific output power is achieved or it results to LD degradation. It is advised that sufficient measure of heat dissipation should be taken so that LD's maximum operating temperature is not exceeded during actual operation.

# **Optical and Electrical Characteristics (Tc=25°C)**

Parameter	Symbol	Min	Тур	Мах	Unit	Test Condition
Threshold current	lth	-	200	250	mA	-
Operating current	Іор	-	600	700	mA	Po=450mW
Operating voltage	Vop	-	2.2	2.6	V	Po=450mW
Beam divergence Parallel to the junction	θ//	1	8.5	20	0	Po=450mW, FWHM
Beam divergence Perpendicular to the junction	θ⊥	25	33	40	0	Po=450mW, FWHM
Lasing Wavelength	λρ	632	637	642	nm	Po=450mW

#### Optical Output Power vs. Forward Current 500 Optical output power Po(mW) 400 Tc=0°C 300 Tc=10°Ċ Tc=25°Ċ 200 Tc=40°C 100 0 0 200 400 600 800 1000 Forward current IF(mA) Slope Efficiency vs. Case Temperature 1.4 1.2 Slope efficiency ns(mW/mA) 1.0 0.8 0.6 0.4 0.2 0 0 10 20 30 40 Case temperature Tc(°C) 655 Po=450mW

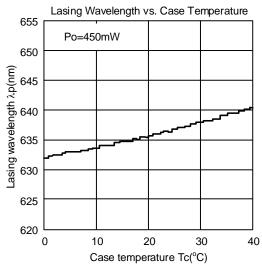
# **Typical Characteristic Curves**



Threshold Current vs. Case temperature

1000

100



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